

GRF2133

Ultra-High Gain LNA Tuning Range: 0.1 to 2.7 GHz



Features

Reference: 5.0V/60mA/700 MHz

Gain: 40.0 dBOP1dB: 20.0 dBmOIP3: 31.0 dBm

NF: 0.70 dB

Reference: 5.0V/60mA/1950 MHz

Gain: 28.0 dB
OP1dB: 20.0 dBm
OIP3: 31.0 dBm
NF: 0.60 dB

Reference: 5.0V/60mA/2500 MHz

Gain: 23.5 dB
OP1dB: 20.0 dBm
OIP3: 30.0 dBm
NF: 0.75dB

Internally Matched

Unconditionally Stable

Flexible Biasing

Process: GaAs pHEMT

Applications

High Gain LNA

Cellular Boosters / Repeaters

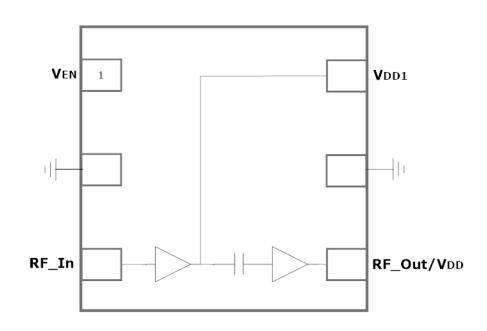
Linear Driver Amplifier

Product Description

GRF2133 is a broadband linear gain block featuring ultra-high gain and sub 0.85 dB noise figure for small cell, cellular booster, wireless infrastructure and other high performance applications.

Configured as a linear driver, LNA or cascaded gain block, it offers high levels of reuse both within a design and across platforms. The device is operated from a supply voltage of 1.8 to 5.0 V with a selectable Iddq range of 35 to 120 mA for optimal efficiency and linearity.

Consult with the GRF applications engineering team for custom tuning/evaluation board data, device sparameters and for applications with Vdd < 2.7 volts.



1.5 x 1.5 mm DFN-6



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Absolute Ratings:

| Parameter | Symbol | Min. | Max. | Unit |
|---|-----------------------|------|------|------|
| Supply Voltage | V _{DD} | 0 | 6.0 | V |
| RF Input Power: (Load VSWR < 2:1; V _D : 5.0 volts) | P _{IN MAX} | | 23 | dBm |
| Operating Temperature (Package Heat Sink) | Тамв | -40 | 105 | °C |
| Maximum Channel Temperature (MTTF > 10^6 Hours) | Тмах | | 170 | °C |
| Maximum Dissipated Power | P _{DISS MAX} | | 700 | mW |
| Electrostatic Discharge: | | | | |
| Charged Device Model: | CDM | 1500 | | V |
| Human Body Model: | HBM | 250 | | V |
| Storage: | | | | |
| Storage Temperature | T _{STG} | -65 | 150 | °C |
| Moisture Sensitivity Level | MSL | | 1 | |



Caution! ESD Sensitive Device



Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

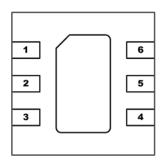
Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF2133 landing page: Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

Link to manufacturing note



Ultra-High Gain LNA Tuning Range: 0.1 to 2.7 GHz

Pin Out (Top View)



Pin Assignments:

| Pin | Name | Description | Note |
|-------------|------------------|----------------------|---|
| 1 | Venable | Enable Voltage Input | Venable and series resistor set IDDQ. Venable < 0.2 volts disables device. On- die pull-down resistor will turn the part off if this node is allowed to float. |
| 2 | NC | No Connect or Ground | No internal connection to die |
| 3 | RF_In | LNA RF input | External DC block required. |
| 4 | RF_Out/VDD | LNA RF output | V _{DD} applied to this pin. External DC block required. |
| 5 | NC | No Connect or Ground | No internal connection to die |
| 6 | V _{DD1} | Bias Supply | Typically tied to V_{DD} via an external resistor or an inductor (for $V_{DD} < 4.0$ volts). Tying to V_{DD} allows for the re-use of M8 for the required de-coupling |
| PKG BASE | GND | Ground | Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page. |



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Nominal Operating Parameters:

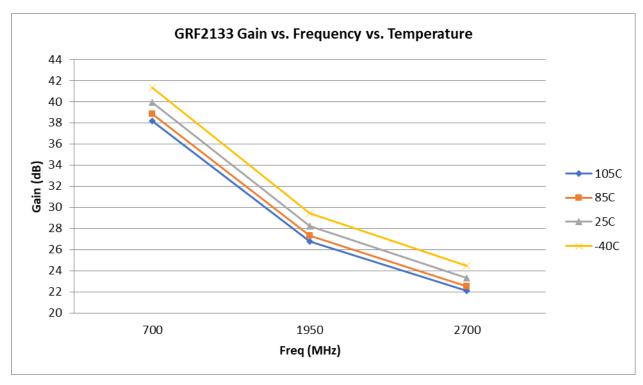
| Parameter | Symbol | 5 | Specification | | Unit | Condition | |
|--|-------------------|------|-------------------|------|-------|---|--|
| raiailletei | Symbol | Min. | Тур. | Max. | Ullit | Condition | |
| Test Frequency | F _{TEST} | | 1950 | | MHz | $V_{DD} = 5.0 \text{ V}, T_A = 25 ^{\circ}\text{C}$ | |
| Gain | S21 | 26.5 | 28.0 | | dB | | |
| Output 3rd Order Intercept | OIP3 | | 31.0 | | dBm | +2.0 dBm P _{OUT} per tone at 2 MHz Spacing (1949 and 1951 MHz) | |
| Output 1dB Compression Power | OP1dB | 18.0 | 20.0 | | dBm | | |
| Evaluation Board Noise Figure | NF | | 0.60 | 0.80 | dB | | |
| Switching Rise Time | T _{RISE} | | 10 | | us | | |
| Switching Fall Time | T _{FALL} | | 200 | | ns | | |
| Supply Current | I _{DD} | | 60 | | mA | | |
| Enable Current | lenable | | 2.0 | | mA | | |
| Disabled Mode | | | | | | | |
| Leakage Current | Ileakage | | 1 | | uA | VDD: 5.0V; VENABLE: 0.0V | |
| Thermal Data | | | | | | | |
| Thermal Resistance: (Infra-Red Scan) | Θјс | | 65 | | °C/W | On standard Evaluation Board | |
| Channel Temperature @ +85 C Reference (Package heat sink) | TCHANNEL | | 105 (See note) | | °C | V _{DD} : 5.0 V; I _{DDQ} : 60 mA; No RF; P _{DISS} : 300 mW | |

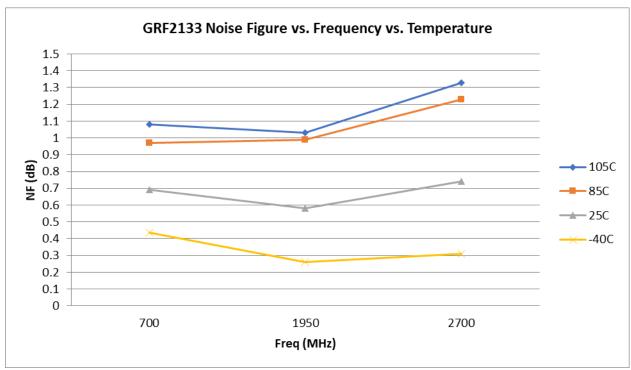
Note: MTTF >10^6 hours for TCHANNEL < =170 degrees C.



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GRF2133 Evaluation Board Performance; (5V/60 mA)

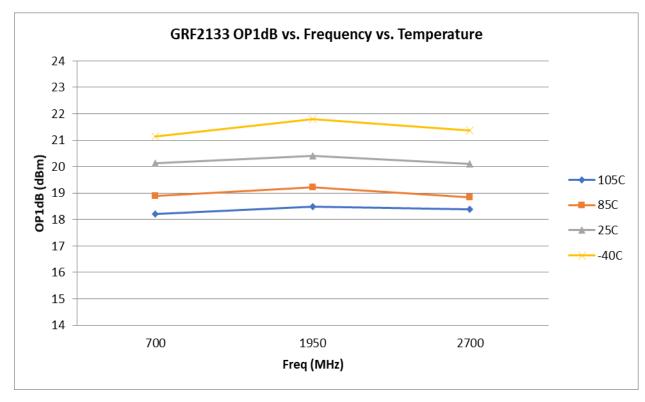


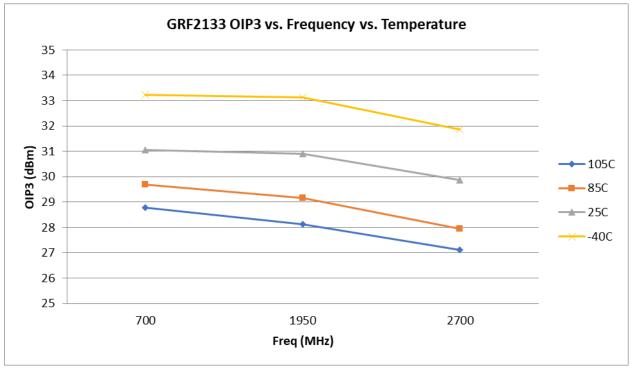




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GRF2133 Evaluation Board Performance; (5V/60 mA)





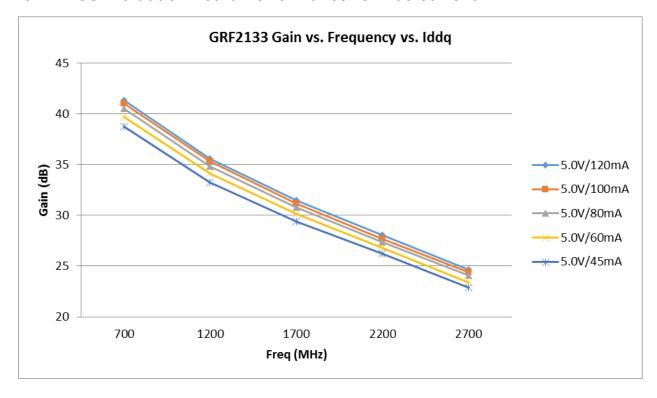


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GRF2133 Evaluation Board Performance vs. Bias Current:



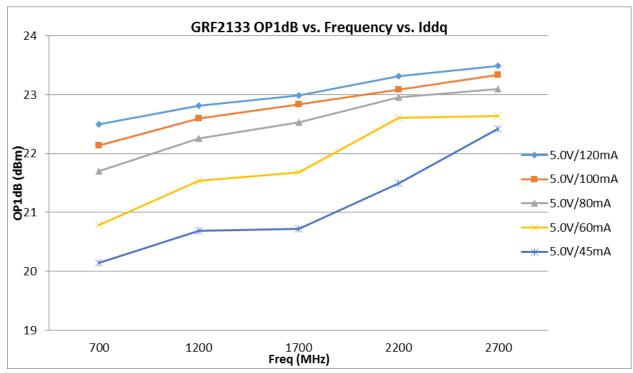


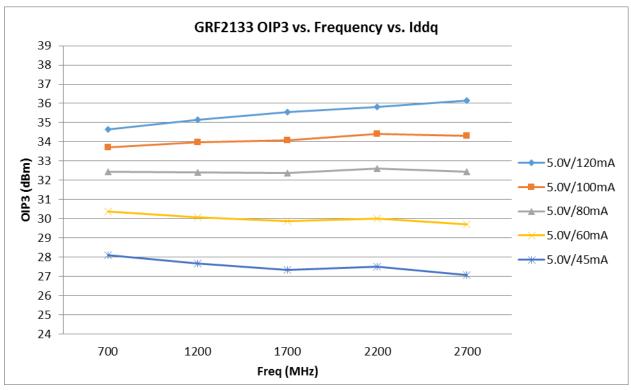
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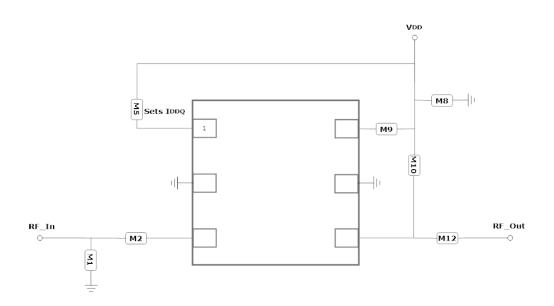




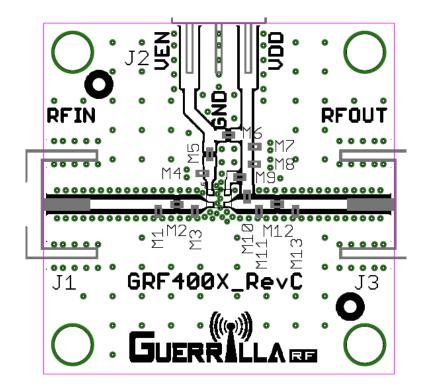


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GRF2133 Application Schematic (700–2700 MHz)



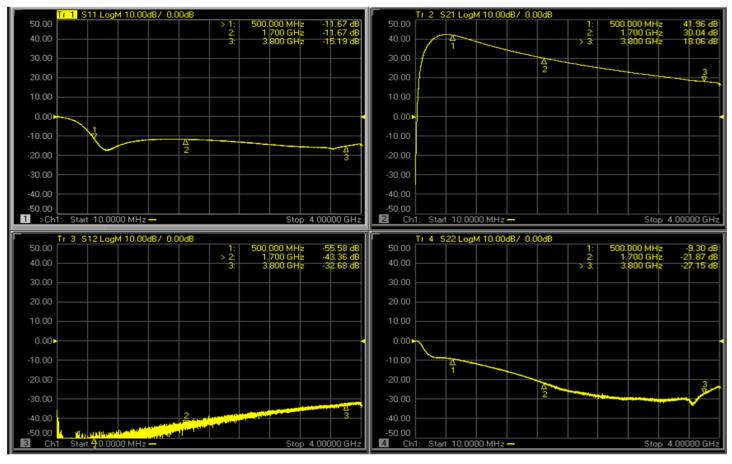
GRF2133 Evaluation Board Assembly Drawing

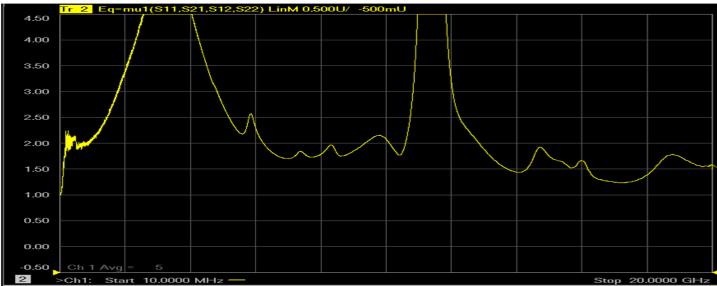


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GRF2133 Evaluation Board S-Pars and Stability Mu Factor: (5.0V/60mA)





Note: Mu factor >= 1.0 implies unconditional stability.

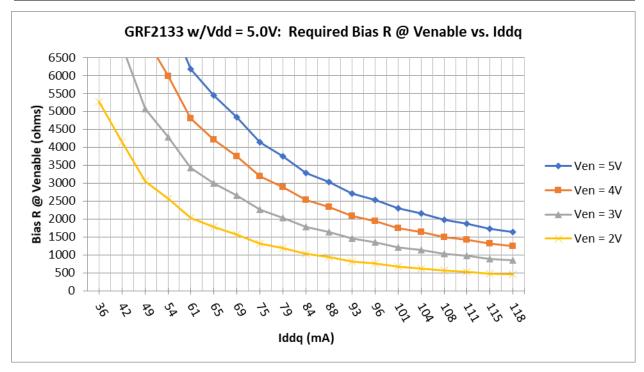
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Ultra-High Gain LNA Tuning Range: 0.1 to 2.7 GHz

GRF2133 Evaluation Board BOM: (0.7 to 2.7 GHz)

| Component | Туре | Manufacturer | Family | Value | Package Size | Substitution |
|-----------|-----------|--------------|---------|-----------|--------------|--------------|
| M1 | Inductor | Murata | LQP/LQG | 18 nH | 0402 | ok |
| M2 | Capacitor | Murata | GJM | 33 pF | 0402 | ok |
| M5 | Resistor | Various | 5% | Sets Iddq | 0402 | ok |
| M8 | Capacitor | Murata | GRM | 0.1 uF | 0402 | ok |
| M9 | Resistor | Various | 5% | 75 ohms | 0402 | ok |
| M10 | Inductor | Murata | LQP/LQG | 33 nH | 0402 | ok |
| M12 | Capacitor | Murata | GJM | 33 pF | 0402 | ok |

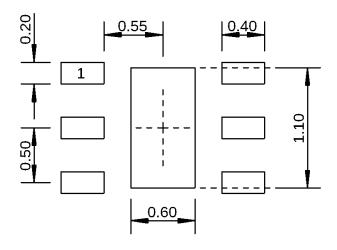




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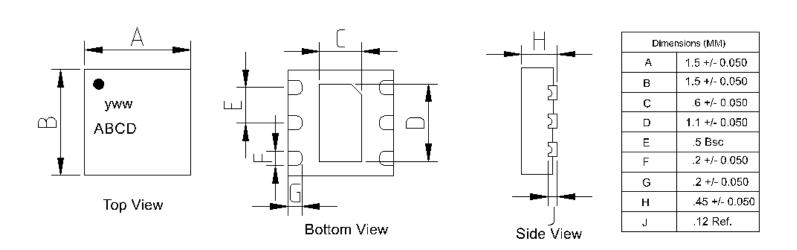
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Dimensions in millimeters

1.5 mm DFN-6 Suggested PCB Footprint (Top View)



1.5 mm DFN-6 Package Dimensions



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| Data Sheet Release Status: | Notes |
|----------------------------|---|
| Advance | S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices. |
| Preliminary | All data based on evaluation board measurements in the Guerrilla RF Applications Lab. |
| Released | All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included. |

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

Revision Date: 05/30/19

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